

3MHz, Rail-to-Rail I/O CMOS Op Amps

Feature

- Stable 3MHz GBWP with Low I_Q of Only 480 μ A Typical per Amplifier
- Offset Voltage: +/-2mV Maximum
- High Slew Rate: 3.7V/μs
- Input Bias Current: 1pA Typical
- CMRR/PSRR:100dB/100dB
- Settling time to 0.1% with 2V Step: 0.46us
- Beyond the Rails Input Common-Mode Range
- Output Swing to within 10mV Typical of each Rail
- No Phase Reversal for Overdriven Inputs
- Supply Voltage Range: 2.1V to 5.5V
- -40°C to 125°C Operation Range
- Green, Popular Type Package

Applications

- Active Filters, ASIC Input or Output Amplifier
- Sensor Interface
- Smoke/Gas/Environment Sensors
- Portable Instruments and Mobile Device
- Audio Output
- PCMCIA Cards
- Battery or Solar Power Systems
- Medical Equipment
- Piezo Electrical Transducer Amplifier

General Description

The HT2358A is CMOS dual op-amps with low offset, stable high frequency response, low power, low supply

voltage, and rail-to-rail inputs and outputs. $$_{0\mu A}$$ HT2358A has a high gain-bandwidth product of

3MHz, $3.7V/\mu s$ slew rate while consuming only 48

of supply current per amplifier. The maximum input

offset voltage is 2mV for HT2358A. Beyond the rail input The

and rail-to-rail output characteristics allow the full power-supply voltage to be used for signal range. operating range is from 2.5V to 5.5V.

This combination of features makes the HT2358A

superior among rail-to-rail input/output CMOS op to

amps in its power class. It is specified over the extended industrial temperature rang -40 $^{\circ}C$ $_{\text{-in}}$ +125 $^{\circ}C.$

The HT2358A can be used as cost-effective plug replacements for many commercially available op amps to reduce power and improve input/output range and performance.



Absolute Maximum Ratings

(If Out of these ratings, the filter may be fail or damaged)

Table 1				
Symbol	parameter	rating	units	
VDD	Power supply	6	V	
Τ _Α	Operating ambient Temperature Range	-40~+125	C°	
Тѕтб	Storage Temperature	-65~+150	°C	

Recommended Operating Conditions

Table 2

Symbol	parameter	rating	units
VDD	Power supply	2.5~5.5	V
T _A	Operating ambient Temperature Range	-40~+125	S°



Electrical Characteristics

Symbol	Parameter		Spec			Units
		Min	Тур	Max		
VCC	Operating Supply Voltage		2.5	5	5.5	V
Vos	Input Offset Voltage		-2	+/-0.6	+2	mV
Vos_tc	Input Offset voltage Tem	p Drift		1.6		μV/°C
en	Input Voltage Noise Dens	sity: f=1KHz		25		nV/VHz
Cin				1.5		рF
		Common Mode		3.0		
Rin	Input Resistance		>100			GΩ
Ι _Q	Quiescent Current per Amplifier			480	790	uA
lout	Output Current			50		mA
Vin_cm	Common mode Input voltage		0		VDD-0.1	V
Vol	Output Voltage from supply Swing			10		mV
CMRR	Common Mode Rejection Ratio			100		dB
lsc	Output short-circuit current			80		mA
PM	Phase Margin			65		٥
GM	Gain Margin			-10		dB
GBWP	Gain-Bandwidth Product			3		MHz
PSRR	Power supply rejection ratio: 1Hz			100		dB
		1KHz		72		
ts	Settling time, 1.5V to 3.5V, Unity Gain: 0.1%			0.46		μs
SR	Slew Rate			3.7		μs

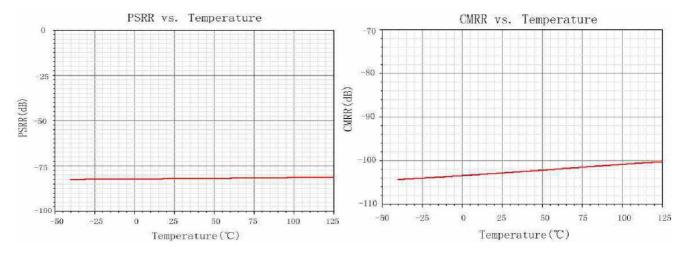
Specifications are at T_A=+27 $^{\circ}\!C$, VDD=5V, V_CM=V_OUT=VDD/2, RL=10Kohm, CL=100pF



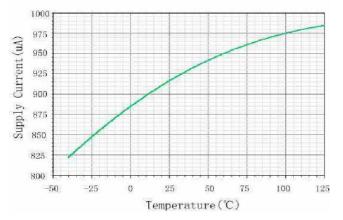


Typical performance characteristics

At T_A =+27°C, Vdd=5V, V_{CM}=V_{OUT}=VDD/2 RL=10Kohm CL=100pF



Quiescent Current vs. Temperature





PAD Definition

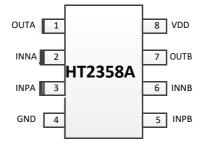


Fig 2. Pad definition of HT2358A

Table 7. Pad definition

Name	I/O	Analog/Digital	Description
INP	I	А	Non-Inverting Input of Amplifier. Voltage range of this pin
			can go from 0 to VDD.
GND	GROUND	GROUND	Ground pin. Connect to the most negative supply, ALL GND
			pads are connected on die.
INN	I	А	Inverting Input of Amplifier. This pin has same voltage
			range as INP.
OUT	0	А	Amplifier Output. The voltage range extends to within
			millivolts of each supply rail.
VDD	POWER	POWER	Power supply (5V) , connect to positive voltage supply



Application Circuits

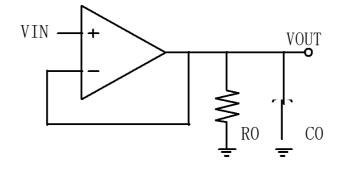


Fig.3 Applications Circuits of HT2358A



(**DIP8**)



Dimension, mm		
MIN MAX		
8.51	10.16	
6.1	7.11	
	5.33	
0.36	0.56	
1.14	1.78	
2.54		
7.62		
0 °	10 °	
2.92	3.81	
7.62	8.26	
0.2	0.36	
0.38		
	MIN 8.51 6.1 0.36 1.14 2. 7. 0° 2.92 7.62 0.2	



 Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

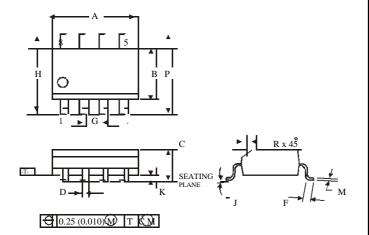
⊕ 0.25 (0.010) M T

T- SEATING PLANE

K

М

в



NOTES:

- 1. Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.

(SOP8)



	Dimension, mm		
Symbol	MIN	MAX	
Α	4.8	5	
В	3.8 4		
С	1.35 1.75		
D	0.33 0.51		
F	0.4 1.27		
G	1.27		
Н	5.72		
J	0° 8°		
K	0.1 0.25		
Μ	0.19 0.25		
Р	5.8	6.2	
R	0.25 0.5		

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